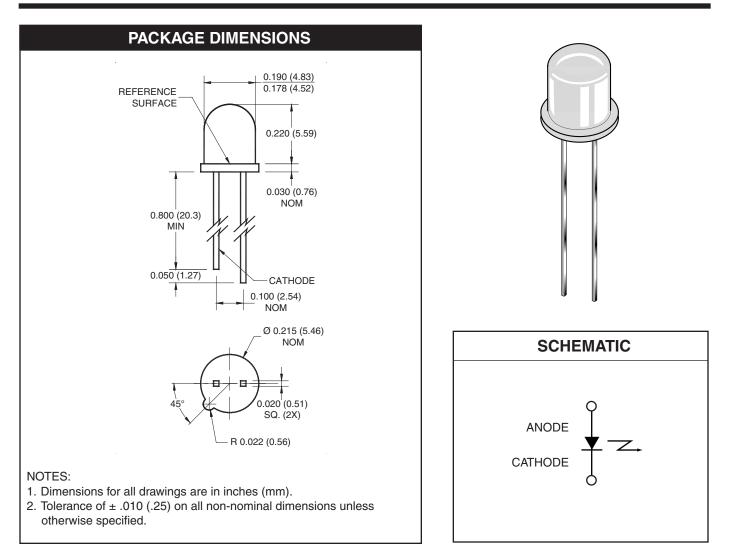


PLASTIC INFRARED LIGHT EMITTING DIODE

QED422 QED423



DESCRIPTION

The QED422/423 is an 880 nm AlGaAs LED encapsulated in a clear, purple tinted, plastic TO-46 package.

FEATURES

- λ= 880 nm
- Chip material = AlGaAs
- Package type: Plastic TO-46
- Matched Photosensor: QSD722/723/724
- Medium Wide Emission Angle, 30°
- High Output Power
- · Package material and color: clear, purple tinted, plastic



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ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)							
Parameter	Symbol	Rating	Unit				
Operating Temperature	T _{OPR}	-40 to + 100	°C				
Storage Temperature	T _{STG}	-40 to + 100	°C				
Soldering Temperature (Iron) ^(2,3,4)	T _{SOL-I}	240 for 5 sec	°C				
Soldering Temperature (Flow) ^(2,3)	T _{SOL-F}	260 for 10 sec	°C				
Continuous Forward Current	I _F	100	mA				
Reverse Voltage	V _R	5	V				
Power Dissipation ⁽¹⁾	P _D	200	mW				

NOTES:

1. Derate power dissipation linearly 2.67 mW/°C above 25°C.

2. RMA flux is recommended.

3. Methanol or isopropyl alcohols are recommended as cleaning agents.

4. Soldering iron 1/16" (1.6 mm) minimum from housing

ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C)								
Parameter	Test Conditions	Symbol	Min	Тур	Max	Units		
Peak Emission Wavelength	I _F = 100 mA	λ _{PE}		880	_	nm		
Emission Angle	I _F = 100 mA	201/2	_	30	—	Deg.		
Forward Voltage	I _F = 100 mA, tp = 20 ms	V _F	_	_	1.8	V		
Reverse Current	V _R = 5 V	I _R	_	_	10	μA		
Radiant Intensity QEC522	I _F = 100 mA, tp = 20 ms	١ _E	10	_	40	mW/sr		
Radiant Intensity QEC523	I _F = 100 mA, tp = 20 ms	١ _E	20	_	_	mW/sr		
Rise Time	I _F = 100 mA	t _r		800	—	ns		
Fall Time		t _f		800	—	ns		



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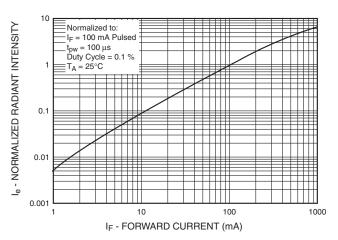


Fig. 1 Normalized Radiant Intensity vs. Forward Current



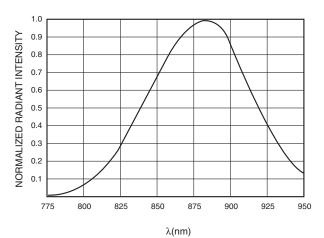


Fig. 2 Forward Voltage vs. Ambient Temperature

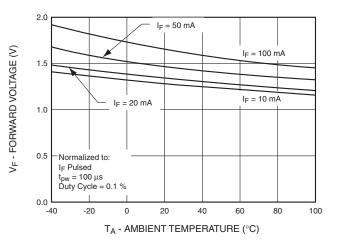
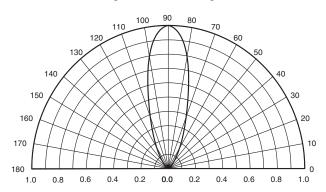


Fig. 4 Radiation Diagram





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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.